L Number	Hits	Search Text	DB	Time stamp
–	480	156/345.33 156/345.34 156/345.29 156/345.38 156/345.26	USPAT	2003/09/05 12:49
–	978	134/113 156/345.18 156/345.21	USPAT	2003/09/05 12:49
–	2	"edge bead" and (134/113 156/345.18 156/345.21)	USPAT	2004/02/20 14:48
–	482	156/345.33 156/345.34 156/345.29 156/345.38 156/345.26	USPAT	2003/09/05 12:49
–	980	134/113 156/345.18 156/345.21	USPAT	2003/09/05 12:58
–	1461	(156/345.33 156/345.34 156/345.29 156/345.38 156/345.26) (134/113 156/345.18 156/345.21)	USPAT	2003/09/05 12:58
–	191	((156/345.33 156/345.34 156/345.29 156/345.38 156/345.26) (134/113 156/345.18 156/345.21)) and suc$4	USPAT	2003/09/05 12:58
–	163431	resist or (((dry plasma) with etch$3) and (mask))	USPAT	2003/09/05 12:59
–	27	(((156/345.33 156/345.34 156/345.29 156/345.38 156/345.26) (134/113 156/345.18 156/345.21)) and suc$4) and ((resist or (((dry plasma) with etch$3) and (mask))) and ((156/345.33 156/345.34 156/345.29 156/345.38 156/345.26) (134/113 156/345.18 156/345.21)))	USPAT	2003/09/05 12:59
–	214	(resist or (((dry plasma) with etch$3) and (mask))) and ((156/345.33 156/345.34 156/345.29 156/345.38 156/345.26) (134/113 156/345.18 156/345.21))	USPAT	2003/09/05 13:10
–	1516	"edge bead"	USPAT	2004/02/20 14:48
–	408	"edge bead" and (wafer substrate semiconductor)	USPAT	2004/02/20 14:49